

View Online at <https://aerobasegroup.com/nsn/5961-01-006-8026>

Inclosure Material:

Glass all semiconductor device diode

Overall Length:

0.175 inches all semiconductor device diode

Terminal Length:

1.000 inches all semiconductor device diode

Overall Diameter:

0.075 inches all semiconductor device diode

Function For Which Designed:

Switching

Internal Configuration:

Junction contact all semiconductor device diode

Internal Junction Configuration:

Pin all semiconductor device diode

Component Function Relationship:

Matched

Component Name And Quantity:

4 semiconductor device diode

Mounting Method:

Terminal all semiconductor device diode

Semiconductor Material:

Silicon all semiconductor device diode

Voltage Rating In Volts Per Characteristic:

80.0 breakdown voltage, dc all semiconductor device diode

Power Rating Per Characteristic:

250.0 milliwatts small-signal input power, common-collector absolute all semiconductor device diode

Capacitance Rating In Picofarads:

0.18 all semiconductor device diode

Maximum Operating Temperature Per Measurement Point:

150.0 degrees celsius junction all semiconductor device diode

Test Data Document:

10001-2836122 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

2 uninsulated wire lead all semiconductor device diode

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

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